

PRELIMINARY AMENDMENT

TO:

COMMISSIONER OF PATENTS AND TRADEMARKS

Washington, D. C. 20231

FROM:

George O. Saile (Reg. No. 19,572)

20 McIntosh Drive

Poughkeepsie, NY 12603

DATE:

17 September 2001

REF:

APPLICANT

Chiang et al.

SERIAL NO.

09/325,951

ART UNIT

2812

FILING DATE : 04/06/99

ATT'Y NO.

: TSMC 98-262

EXAMINER

: R. Pompey

TITLE

: Method for Forming High Purity Silicon Oxide Field

Oxide Isolation Region

Sir:

In response to an advisory action mailed on 07 August 2001, please consider the following amendments and remarks pertaining to the above referenced application.

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class mail in an envelope addressed to the Commissioner of Patents and Trademarks, Washington, D. C. 20231 on 21 September 2001

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